# **INC1001AC1**

FOR GENERAL PURPOSE HIGH CURRENT DRIVE APPLICATION SILICON NPN EPITAXIAL TYPE

### **DESCRIPTION**

INC1001AC1 is a silicon NPN epitaxial type transistor. It is designed with high collector current and small  $V_{\text{CE(sat)}}$ .

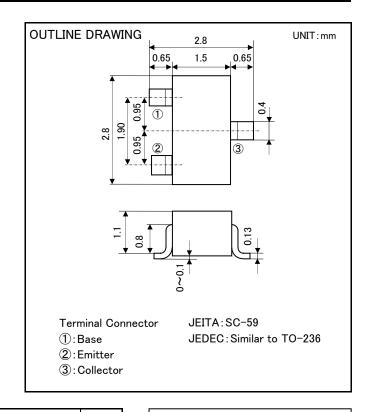
### **FEATURE**

- ·Super mini package for easy mounting
- •High collector current(I<sub>C</sub>=500mA)
- •Low collector saturation voltage

 $(V_{CE(sat)} < 0.3V_{max}; IC=100mA, IB=10mA)$ 

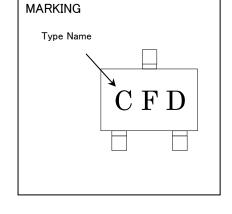
### **APPLICATION**

For switching, Small type motor drive



### MAXIMUM RATING(Ta=25°C)

SYMBOL	PARAMETER	RATING	UNIT	
V <sub>CBO</sub>	Collector to Base voltage	80	٧	
$V_{EBO}$	Emitter to Base voltage	7	٧	
$V_{\text{CEO}}$	Collector to Emitter voltage	80	٧	
Ιc	Collector current	0.5	Α	
P <sub>c</sub>	Collector dissipation(Ta=25°C)	200	mW	
		500(*)		
$T_{j}$	Junction temperature	+150	°C	
$T_{stg}$	Storage temperature	-55 <b>~</b> +150	°C	



## ELECTRICAL CHARACTERISTICS (Ta=25°C)

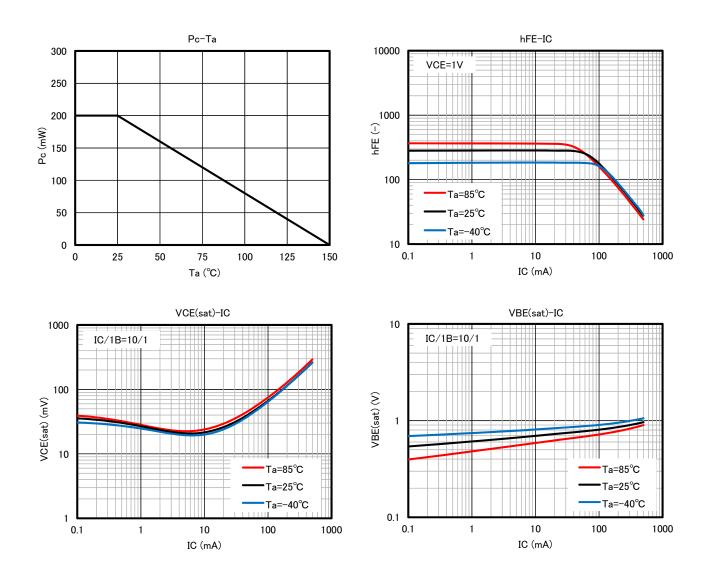
ELECTRICAL CHARACTERISTICS (Ta-25 C)										
SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT				
			MIN	TYP	MAX	UNIT				
$V_{(BR)CBO}$	C to B breakdown voltage	$I_{c}=100 \mu A, I_{E}=0$	80	_	1	V				
$V_{(BR)EBO}$	E to B breakdown voltage	$I_{E}=100 \mu$ A, $I_{C}=0$	7	_	-	٧				
$V_{(BR)CEO}$	C to E breakdown voltage	I <sub>C</sub> =1mA, I <sub>B</sub> =0	80	_	-	٧				
I <sub>CBO</sub>	Collector cut off current	$V_{CB}$ =80V, I $_{E}$ =0	_	_	0.15	μΑ				
I <sub>EBO</sub>	Emitter cut off current	V <sub>EB</sub> =7V, I <sub>C</sub> =0	_	_	0.15	μΑ				
h <sub>FE1</sub>	DC forward current gain1	VCE=1V, I <sub>c</sub> =10mA	105	_	-	_				
h <sub>FE2</sub>	DC forward current gain2	VCE=1V, I <sub>C</sub> =100mA	95	_	_	_				
V <sub>CE(sat)</sub>	C to E saturation voltage	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA	_	-	0.3	٧				
fT	Gain bandwidth product	VCE=2V, I <sub>E</sub> =-10mA, f=100MHz	100	_	_	MHz				

<sup>\*</sup>Mounted on glass epoxy board(46mm × 19mm × 1mm)

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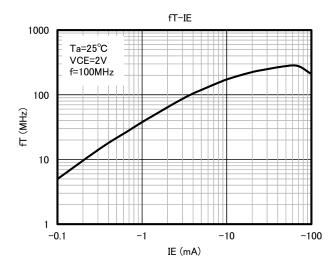
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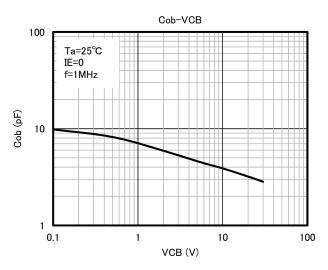
### TYPICIAL CHARACTERISTICS

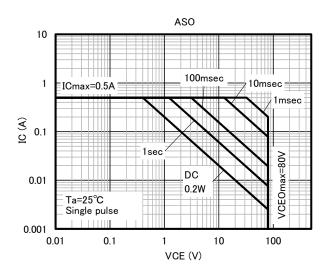


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